

PMCM6501VPE 12 V, P-channel Trench MOSFET

10 August 2015

Product data sheet

1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a 6 bumps Wafer Level Chip-Size Package (WLCSP) using Trench MOSFET technology.

2. Features and benefits

- Low threshold voltage
- Ultra small package: 0.98 × 1.48 × 0.35 mm
- Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection > 2 kV HBM

3. Applications

- Battery switch
- High-speed line driver
- Low-side loadswitch
- Switching circuits

4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	-12	V
V _{GS}	gate-source voltage			-8	-	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-	-8.2	А
Static characteristics							
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -3.0 A; T _j = 25 °C		-	19	25	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

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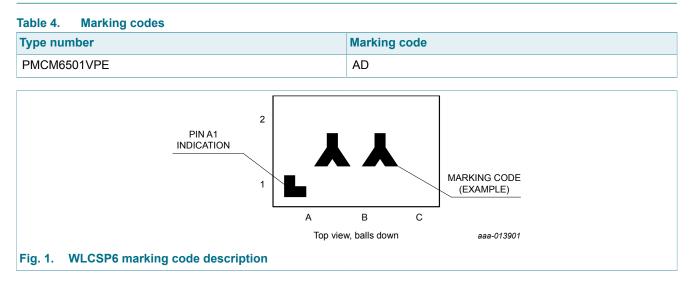
5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
A1	G	gate	1 2	D
A2	S	source		
B1	S	source	в	G (The provide state of the p
B2	S	source		
C1	D	drain		
C2	D	drain	Transparent top view WLCSP6 (OL- PMCM6501VPE)	S 017aaa259

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
PMCM6501VPE	WLCSP6	WLCSP6: wafer level chip-size package; 6 bumps (3 x 2)	OL-PMCM6501VPE				

7. Marking



8. Limiting values

Table 5.Limiting values

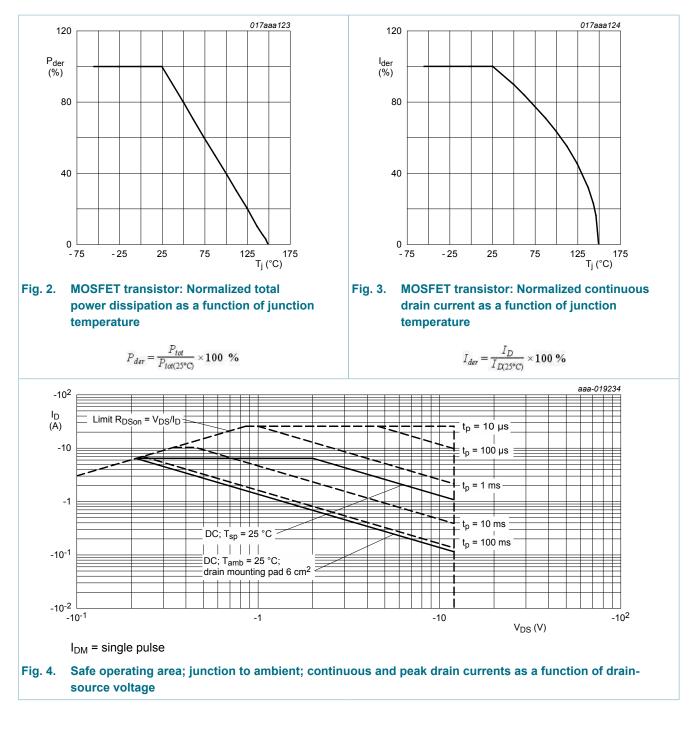
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-12	V
V _{GS}	gate-source voltage			-8	8	V
I _D	drain current	V_{GS} = -4.5 V; T_{amb} = 25 °C; t ≤ 5 s	[1]	-	-8.2	А
		V _{GS} = -4.5 V; T _{amb} = 25 °C	[1]	-	-6.2	А
		V _{GS} = -4.5 V; T _{amb} = 100 °C	[1]	-	-4	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-25	А
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	556	mW
			[1]	-	1300	mW
		T _{sp} = 25 °C		-	12500	mW
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-dra	in diode		1			
I _S	source current	T _{amb} = 25 °C	[1]	-	-1.2	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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9. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to ambient		in free air	[1]	-	180	225	K/W
		[2]	-	65	85	K/W	
		[3]	-	75	95	K/W	
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Product data sheet

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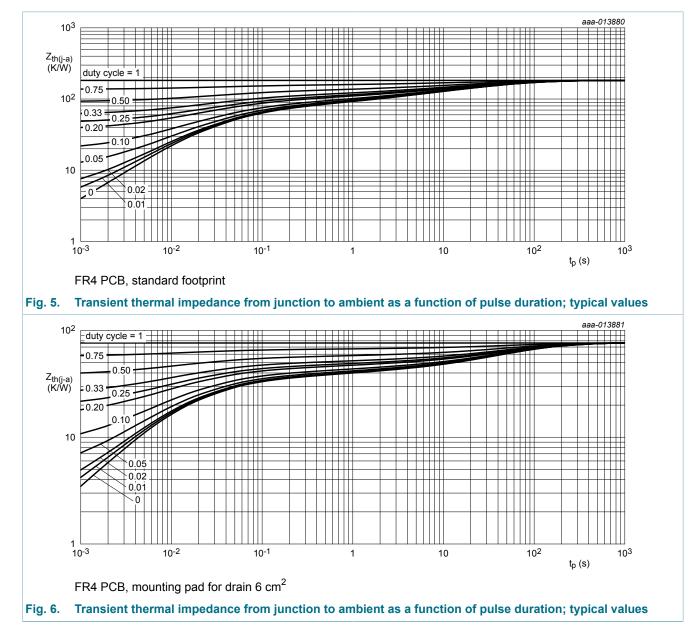
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Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
		in free air; t ≤ 5 s	[3]	-	45	55	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	5	10	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 4-layer 1 cm².

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².



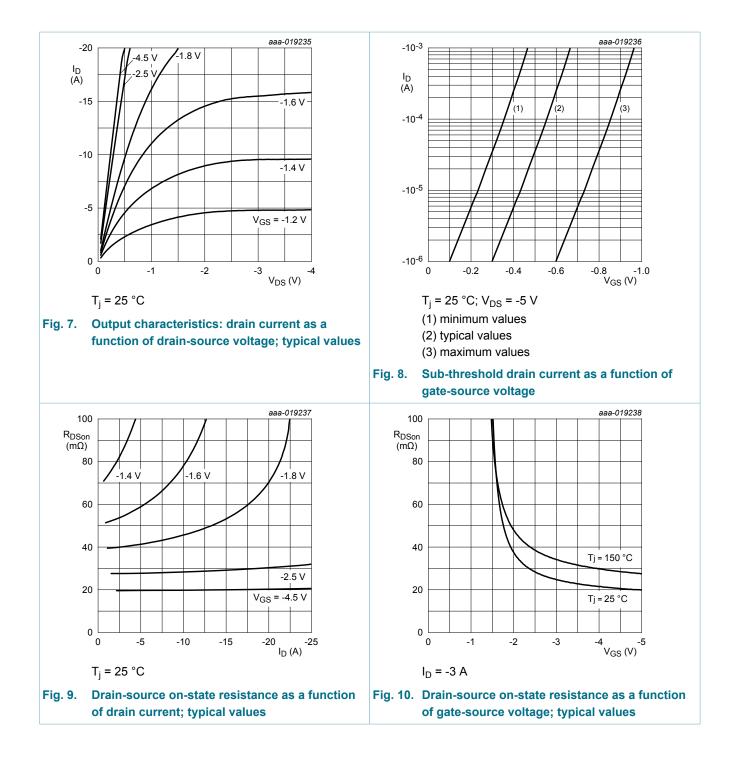
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	I_D = -250 µA; V_{GS} = 0 V; T_j = 25 °C	-12	-	-	V
V _{GSth}	gate-source threshold voltage	I_D = -250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	-0.4	-0.6	-0.9	V
I _{DSS}	drain leakage current	V_{DS} = -12 V; V_{GS} = 0 V; T_j = 25 °C	-	-	-1	μA
I _{GSS}	gate leakage current	V_{GS} = -8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	-10	μA
		V_{GS} = 8 V; V_{DS} = 0 V; T_j = 25 °C	-	-	10	μA
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-1	μA
		V_{GS} = 4.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	1	μA
		V _{GS} = -2.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-200	nA
		V_{GS} = 2.5 V; V_{DS} = 0 V; T_j = 25 °C	-	-	200	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = -4.5 V; I _D = -3.0 A; T _j = 25 °C	-	19	25	mΩ
		V _{GS} = -4.5 V; I _D = -3.0 A; T _j = 150 °C	-	26	34	mΩ
		V _{GS} = -2.5 V; I _D = -3.0 A; T _j = 25 °C	-	25	33	mΩ
		V _{GS} = -1.8 V; I _D = -1.0 A; T _j = 25 °C	-	37	60	mΩ
9 _{fs}	forward transconductance	V_{DS} = -6.0 V; I _D = -3.0 A; T _j = 25 °C	-	13	-	S
R _G	gate resistance	f = 1 MHz	-	12.6	-	Ω
Dynamic ch	aracteristics	I	I			
Q _{G(tot)}	total gate charge	V_{DS} = -6 V; I_{D} = -3 A; V_{GS} = -4.5 V;	-	19.6	29.4	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	2.7	-	nC
Q _{GD}	gate-drain charge		-	5	-	nC
C _{iss}	input capacitance	V _{DS} = -6 V; f = 1 MHz; V _{GS} = 0 V;	-	1400	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	430	-	pF
C _{rss}	reverse transfer capacitance		-	400	-	pF
t _{d(on)}	turn-on delay time	V_{DS} = -6 V; I_{D} = -6 A; V_{GS} = -4.5 V;	-	8	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	51	-	ns
t _{d(off)}	turn-off delay time		-	72	-	ns
t _f	fall time		-	62	-	ns
Source-drai	in diode	1	I			
V _{SD}	source-drain voltage	I _S = -1.2 A; V _{GS} = 0 V; T _i = 25 °C	-	-0.9	-1.2	V

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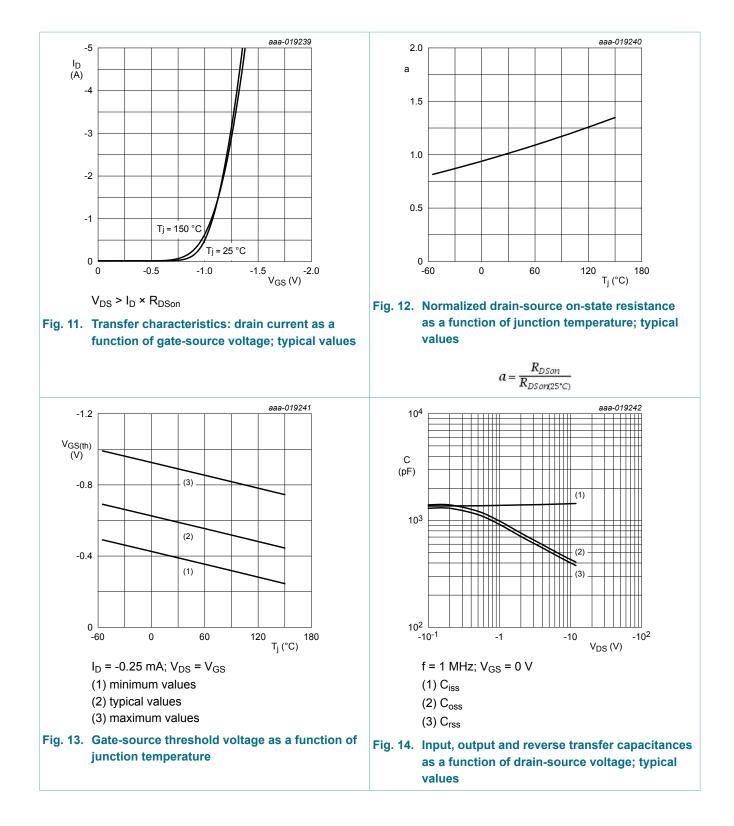


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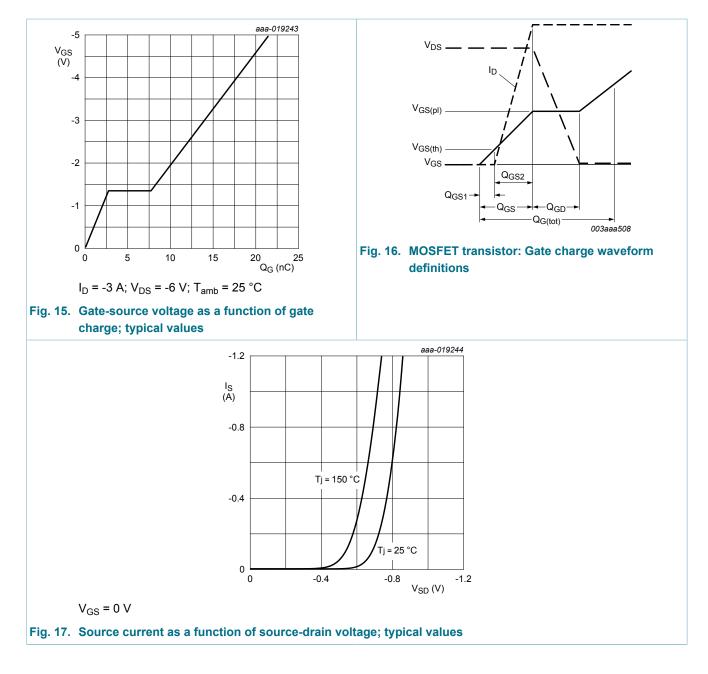
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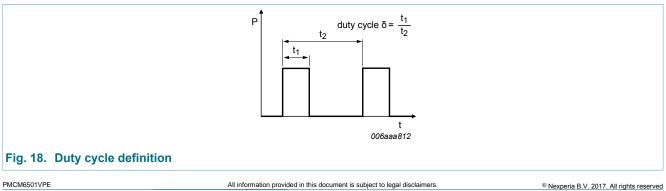
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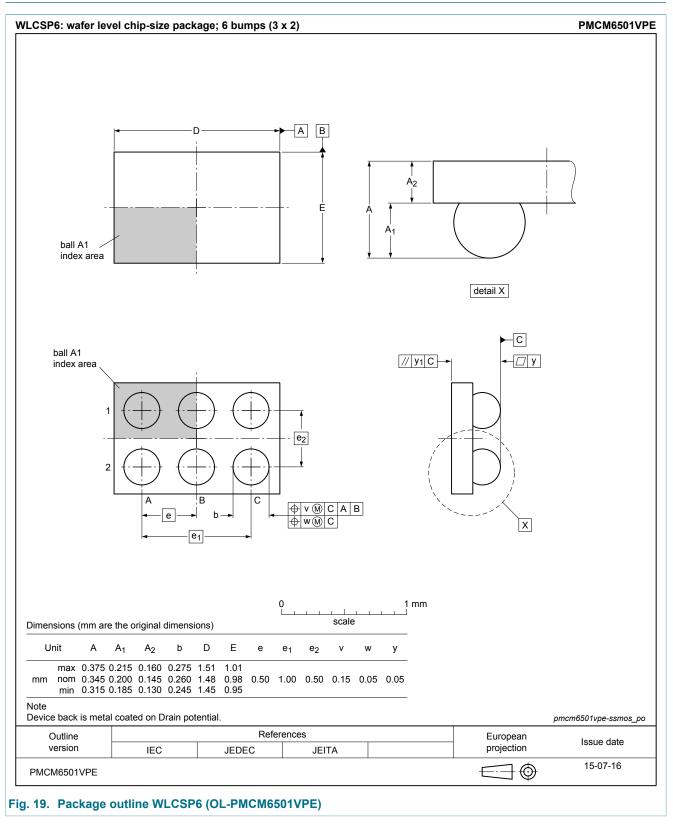
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11. Test information



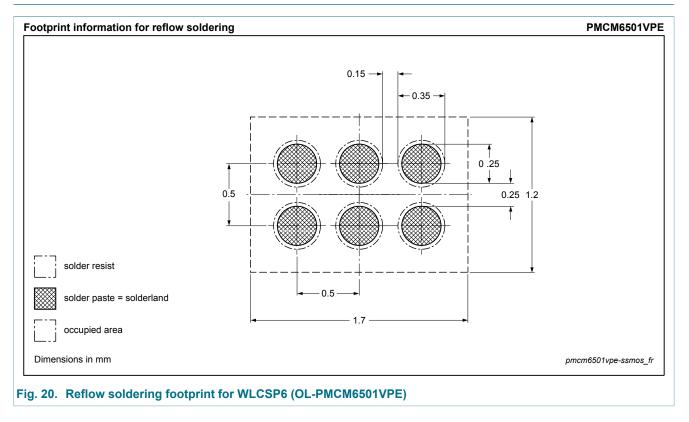
12. Package outline



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13. Soldering



14. Revision history

Table 8. Revision history							
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes			
PMCM6501VPE v.1	20150810	Product data sheet	-	-			

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15. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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